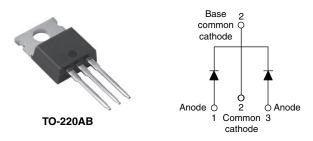




Vishay Semiconductors

Schottky Rectifier, 2 x 20 A



PRODUCT SUMMARY						
Package	TO-220AB					
I _{F(AV)}	2 x 20 A					
V _R	45 V					
V _F at I _F	0.48 V					
I _{RM} max.	115 mA at 125 °C					
T _J max.	150 °C					
Diode variation	Common cathode					
E _{AS}	20 mJ					

FEATURES

- 150 °C TJ operation
- Very low forward voltage drop
- High frequency operation



- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
 COMPLIANT
 COMPLIANT
- Guard ring for enhanced ruggedness and long
 FREE
 Available
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

This center tap Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	40	A			
V _{RRM}		45	V			
I _{FSM}	t _p = 5 μs sine	1240	A			
V _F	20 A_{pk} , T_J = 125 °C (per leg)	0.48	V			
TJ	Range	- 55 to 150	°C			

VOLTAGE RATINGS							
PARAMETER	SYMBOL	VS-40CTQ045PbF	VS-40CTQ045-N3	UNITS			
Maximum DC reverse voltage	V _R	45	45	V			
Maximum working peak reverse voltage	V _{RWM}	45	45	v			

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS			
Maximum average forward current per leg		50 % duty cycle at T_{C} = 116 °C, rectangular waveform		20				
See fig. 5 per device	I _{F(AV)}			40				
Maximum peak one cycle non-repetitive surge current per leg	1	5 µs sine or 3 µs rect. pulse Following any rated load condition and with rated		1240	A			
See fig. 7	^I FSM 10 ms sine or 6 ms rect. pulse		V _{RRM} applied	350				
Non-repetitive avalanche energy per leg	E _{AS}	$T_{J} = 25 \text{ °C}, I_{AS} = 3 \text{ A}, L = 4.4 \text{ mH}$		20	mJ			
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _B typical		3	А			

Revision: 26-Aug-11



Vishay Semiconductors

ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS		
Maximum forward voltage drop per leg See fig. 1		20 A	T.I = 25 °C	0.53	V		
	V _{FM} ⁽¹⁾	40 A	1j=23 0	0.68			
	VFM (**	20 A	T.I = 125 °C	0.48			
		40 A	1j = 125 C	0.67			
Maximum reverse leakage current per leg	I _{BM} ⁽¹⁾	$T_J = 25 \text{ °C}$		3	mA		
See fig. 2	IRM \''	T _J = 125 °C	$V_R = Rated V_R$	115	ШA		
Threshold voltage	V _{F(TO)}			0.27	V		
Forward slope resistance	r _t	i j = i j maximum	$T_J = T_J$ maximum		mΩ		
Maximum junction capacitance per leg	CT	V_{R} = 5 V_{DC} (test signal range 100 kHz to 1 MHz) 25 $^{\circ}\text{C}$		2800	pF		
Typical series inductance per leg	L _S	Measured lead to lead 5 m	8.0	nH			
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs		

Note

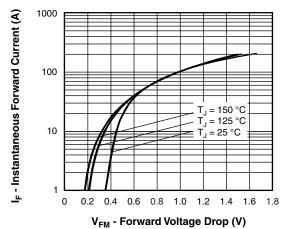
 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range		T _J , T _{Stg}		- 55 to 150	°C		
Maximum thermal resistance, junction to case per leg		D		2.0			
Maximum thermal resistance, junction to case per package		R _{thJC}	DC operation	1.0	°C/W		
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50			
Approvimato wojaht				2	g		
Approximate weight				0.07	oz.		
Mounting torque —	minimum			6 (5)	kgf ⋅ cm		
	maximum	1		12 (10)	(lbf · in)		
Marking device			Case style TO-220AB	40CT	Q045		



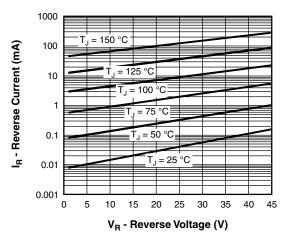
VS-40CTQ045PbF, VS-40CTQ045-N3

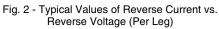
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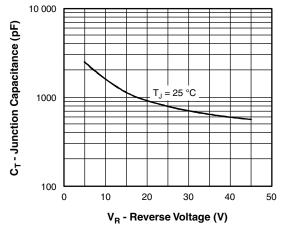


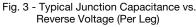


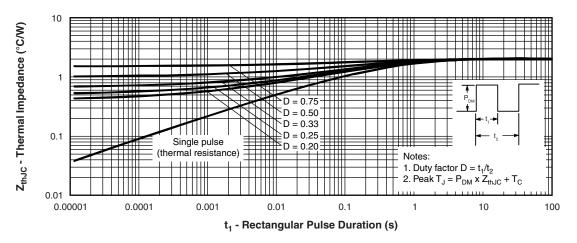


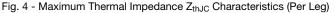










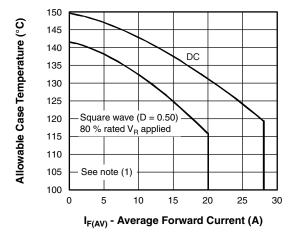


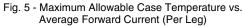
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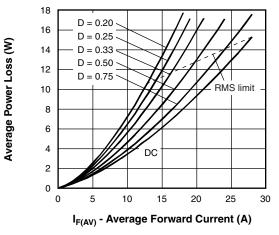


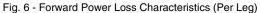
VS-40CTQ045PbF, VS-40CTQ045-N3

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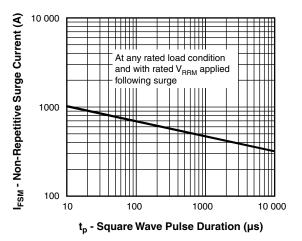


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

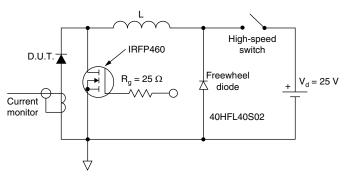


Fig. 8 - Unclamped Inductive Test Circuit

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mbox{Pd} = \mbox{Forward power loss} = \mbox{I}_{F(AV)} \ x \ V_{FM} \ at \ (\mbox{I}_{F(AV)}/D) \ (see \ fig. \ 6); \\ \mbox{Pd}_{REV} = \ \mbox{Inverse power loss} = \ \ V_{R1} \ x \ \ \ I_{R} \ (1 - D); \ \ \ I_{R} \ at \ \ \ \ V_{R1} = \ 10 \ \ \ V \end{array}$

Revision: 26-Aug-11

4

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VS-40CTQ045PbF, VS-40CTQ045-N3



Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code	VS-	40	с	т	Q	045	PbF
		2	3	4	5	6	7
	 Vishay Semiconductors product Current rating (40 = 40 A) Circuit configuration: C = Common cathode Package: T = TO-220 						
	 5 - Schottky "Q" series 6 - Voltage rating (045 = 45 V) 						
	7	• F	PbF = Le	ntal digit ead (Pb)	-free an		

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION							
VS-40CTQ045PbF	50	1000	Antistatic plastic tube				
VS-40CTQ045-N3	50	1000	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?95222					
Part marking information	TO-220AB PbF	www.vishay.com/doc?95225			
Part marking information	TO-220AB -N3	www.vishay.com/doc?95028			



Vishay Semiconductors

TO-220AB

DIMENSIONS in millimeters and inches





.ead	assignments

Diodes

1. - Anode/open 2. - Cathode 3. - Anode

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- ⁽²⁾ Lead dimension and finish uncontrolled in L1
- ⁽³⁾ Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- $^{\left(4\right) }$ Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1

MILLIMETERS INCHES SYMBOL NOTES MIN. MAX. MIN. MAX. 10.51 0.414 10.11 0.398 3,6 Е E1 6.86 8.89 0.270 0.350 6 E2 0.76 0.030 7 --2.41 2.67 0.095 0.105 е 0.208 e1 4.88 5.28 0.192 H1 6.09 6.48 0.240 0.255 6,7 13.52 14.02 0.532 0.552 L L1 3.32 3.82 0.131 0.150 2 ØΡ 3.54 3.73 0.139 0.147 2.60 0.102 Q 3.00 0.118 90° to 93° 90° to 93° θ

Conforms to JEDEC outline TO-220AB

- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline



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